

< Mono : 19.60% – 20.60% >

Dimension 156 mm x 156 mm ± 0.5 mm

Wafer Thickness 200µm ± 30µm
180µm + 30µm / -20µm

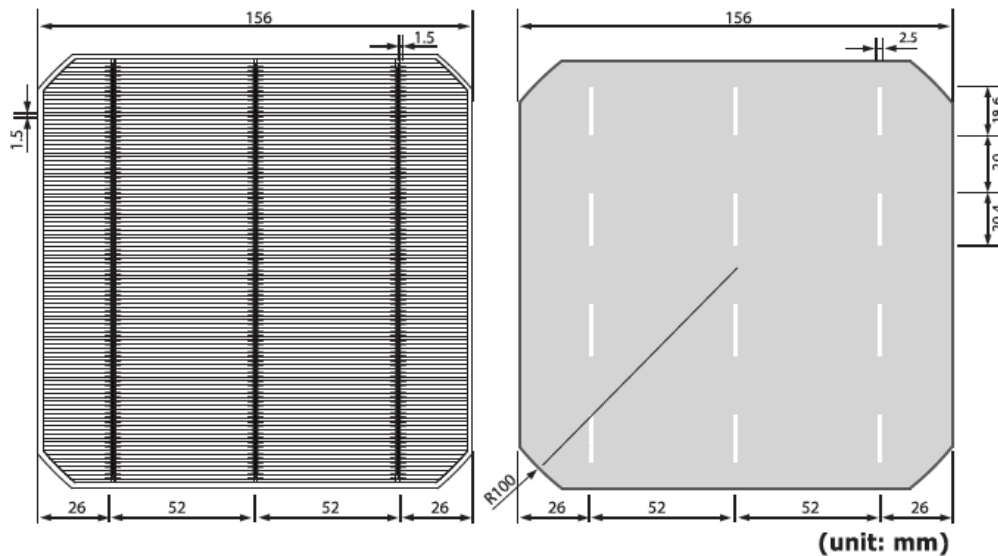
Front(-) Three 1.5mm wide bus bars (silver) with distance 52 mm,
alkaline texturized surface with dark blue silicon nitride AR coating.

Back(+) 2.5mm wide silver/aluminum soldering pads, aluminum local back surface field.

| Efficiency code | 1960 | 1980 | 2000 | 2020 | 2040 | 2060 |
|-----------------|-------|-------|-------|-------|-------|-------|
| Efficiency (%) | 19.6 | 19.8 | 20.0 | 20.2 | 20.4 | 20.6 |
| Pmax (W) | 4.683 | 4.731 | 4.779 | 4.827 | 4.875 | 4.922 |
| Voc (V) | 0.646 | 0.648 | 0.650 | 0.652 | 0.654 | 0.656 |
| Isc (A) | 9.270 | 9.315 | 9.361 | 9.402 | 9.439 | 9.478 |
| Vmp (V) | 0.541 | 0.542 | 0.543 | 0.544 | 0.545 | 0.547 |
| Imp (A) | 8.657 | 8.725 | 8.794 | 8.873 | 8.941 | 8.997 |

*Data under standard testing conditions (STC): 1,000W/m², AM1.5, 25°C, Pmax: Positive power tolerance.

Voltage -2.08 mV/K
Current +4.51 mA/K
Power -0.40 %/K



(Cell Efficiency 20.2 %)

